## HSC88

Silicon Schottky Barrier Diode for Various Detector, Mixer

# **HITACHI**

ADE-208-826 (Z) Rev 0 Nov. 1999

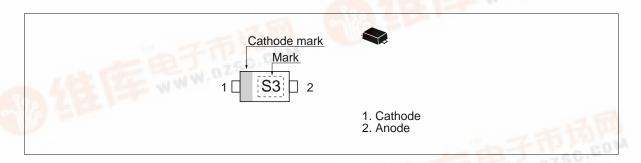
#### **Features**

- Low capacitance. (C = 0.8pF max)
- Low forward voltage.
- <u>Ultra small Flat Package (UFP)</u> is suitable for high density surface mounting and high speed assembly.

#### **Ordering Information**

Type No.	Laser Mark	Package Code	-
HSC88	S3	UFP	

#### **Outline**





### HSC88

### Absolute Maximum Ratings ( $Ta = 25^{\circ}C$ )

Item	Symbol	Value	Unit
Reverse voltage	$V_R$	10	V
Average rectified current	Io	15	mA
Junction temperature	Tj	125	°C
Storage temperature	Tstg	-55 to +125	°C

### Electrical Characteristics (Ta = $25^{\circ}$ C)

Item	Symbol	Min	Тур	Max	Unit	Test Condition
Forward voltage	$V_{F1}$	350		420	mV	I <sub>F</sub> = 1 mA
	$V_{F2}$	500	_	580		I <sub>F</sub> = 10 mA
Reverse current	I <sub>R1</sub>	_	_	0.2	μΑ	$V_R = 2V$
	I <sub>R2</sub>	_		10		V <sub>R</sub> = 10V
Capacitance	С	_	_	8.0	pF	$V_R = 0V$ , $f = 1 MHz$
ESD-Capability*1	_	30	_	_	V	C = 200pF , Both forward and reverse direction 1 pulse.

Notes 1. Failure criterion ;  $I_R \ge 400$ nA at  $V_R = 2$  V

#### **Main Characteristic**

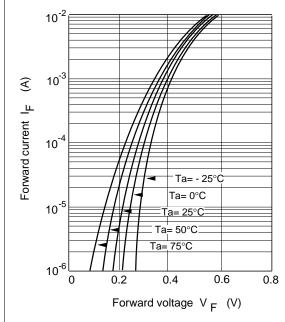
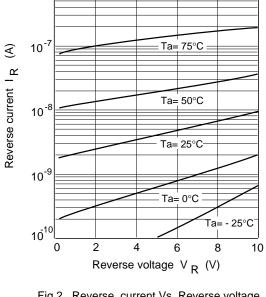


Fig.1 Forward current Vs. Forward voltage



10<sup>-6</sup>ı

Fig.2 Reverse current Vs. Reverse voltage

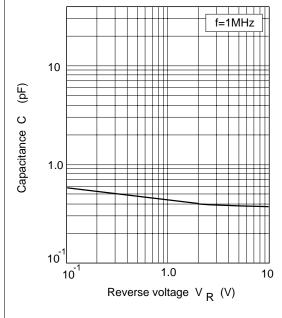
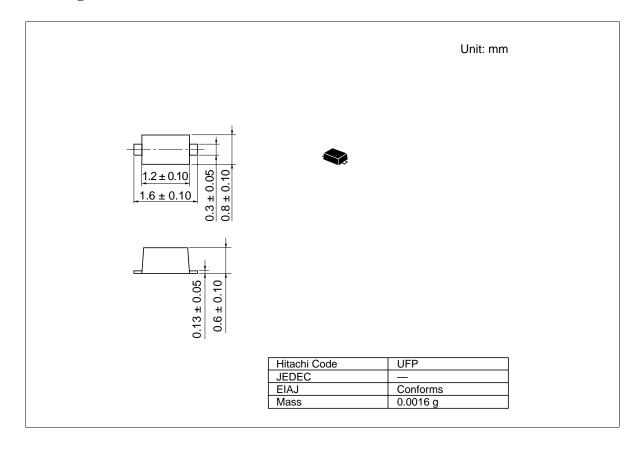


Fig.3 Capacitance Vs. Reverse voltage

### HSC88

### **Package Dimensions**



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